



TPS60150 5-V, 140-mA Charge-Pump

1 Features

- 2.7-V to 5.5-V Input Voltage Range
- Fixed Output Voltage of 5 V
- Maximum Output Current: 140 mA
- 1.5-MHz Switching Frequency
- Typical 90- μ A Quiescent Current at No Load Condition (Skip Mode)
- X2 Charge Pump
- Hardware Enable and Disable Function
- Built-in Soft Start
- Built-in Undervoltage Lockout Protection
- Thermal and Overcurrent Protection
- Available in a 2-mm \times 2-mm 6-Pin SON Package with 0.8-mm Height

2 Applications

- USB On-the-Go (OTG)
- HDMI
- Portable Communication Devices
- PCMCIA Cards
- Mobile Phones, Smart Phones
- Handheld Meters

3 Description

The TPS60150 device is a switched capacitor voltage converter that produces a regulated, low noise, and low-ripple output voltage of 5 V from an unregulated input voltage.

The 5-V output can supply a minimum of 140-mA current.

The TPS60150 device operates in skip mode when the load current falls less than 8 mA under typical condition. In skip mode operation, quiescent current is reduced to 90 μ A.

Only 3 external capacitors are needed to generate the output voltage, therefore saving PCB space.

Inrush current is limited by the soft-start function during power on and power transient states.

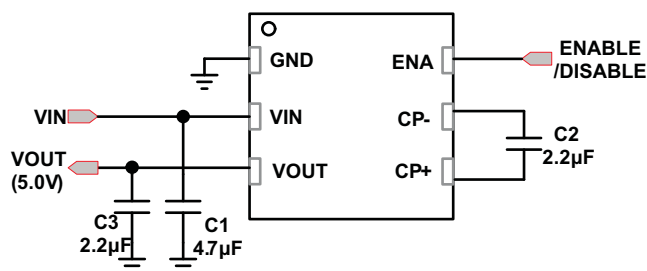
The TPS60150 device operates over a free-air temperature range of -40°C to 85°C . The device is available with a small 2-mm \times 2-mm 6-pin SON package (QFN).

Device Information⁽¹⁾

PART NUMBER	PACKAGE	BODY SIZE (NOM)
TPS60150	WSON (6)	2.00 mm \times 2.00 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

Typical Application Schematic



Efficiency vs Input Voltage

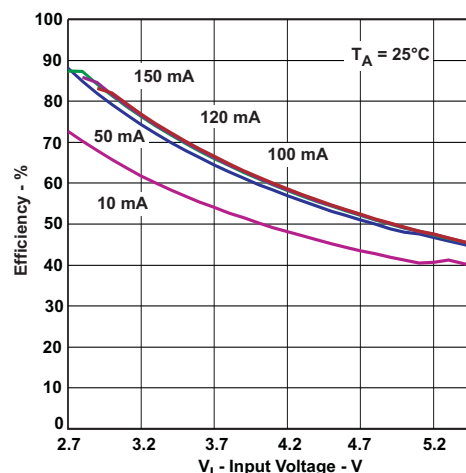


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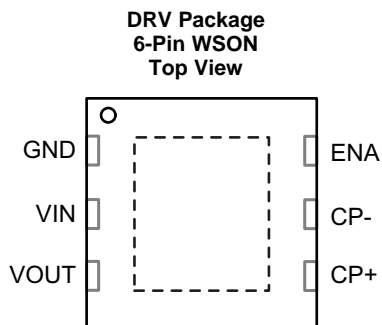
4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (February 2011) to Revision C	Page
<ul style="list-style-type: none"> Added <i>Pin Configuration and Functions</i> section, <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i>, <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section 	1

Changes from Revision A (April 2009) to Revision B	Page
<ul style="list-style-type: none"> Added the Thermal Table and deleted the Dissipation Rating Table 	4

5 Pin Configuration and Functions



Pin Functions

PIN		I/O	DESCRIPTION
NAME	NO.		
CP+	4	—	Connect to the flying capacitor
CP–	5	—	Connect to the flying capacitor
ENA	6	IN	Hardware enable/disable pin (High = Enable)
GND	1	—	Ground
VIN	2	IN	Supply voltage input
VOUT	3	OUT	Output, connect to the output capacitor

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted) ⁽¹⁾

	MIN	MAX	UNIT
V _{IN} Input voltage (all pins)	−0.3	7	V
T _A Operating temperature	−40	85	°C
T _J Maximum operating junction temperature		150	°C
T _{stg} Storage temperature	−55	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under *recommended operating conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

	VALUE	UNIT
V _(ESD) Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾⁽²⁾	±2000
	Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽³⁾	±500

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) The human body model (HBM) is a 100-pF capacitor discharged through a 1.5-kΩ resistor into each pin. The testing is done according to JEDECs EIA/JESD22-A114.
(3) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

	MIN	NOM	MAX	UNIT
V _{IN} Input voltage	2.7		5.5	V
T _A Operating ambient temperature	−40		85	°C
T _J Operating junction temperature	−40		125	°C
C _{in} Input capacitor	2.2			μF
C _o Output capacitor	2.2			μF
C _f Flying capacitor	1			μF

6.4 Thermal Information

THERMAL METRIC ⁽¹⁾		TPS60150	UNIT
		DRV (WSON)	
		6 PINS	
R _{θJA}	Junction-to-ambient thermal resistance	69.1	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	79.8	°C/W
R _{θJB}	Junction-to-board thermal resistance	38.6	°C/W
ψ _{JT}	Junction-to-top characterization parameter	1.2	°C/W
ψ _{JB}	Junction-to-board characterization parameter	38.4	°C/W
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	9.2	°C/W

- (1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

6.5 Electrical Characteristics

$V_{IN} = 3.6\text{ V}$, $T_A = -40^\circ\text{C}$ to 85°C , typical values are at $T_A = 25^\circ\text{C}$, $C1 = C3 = 2.2\text{ }\mu\text{F}$, $C2 = 1\text{ }\mu\text{F}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
POWER STAGE						
V_{IN}	Input voltage range		2.7		5.5	V
V_{UVLO}	Undervoltage lockout threshold			1.9	2.1	V
I_Q	Operating quiescent current	$I_{OUT} = 140\text{ mA}$, Enable = V_{IN}		4.7		mA
I_{Qskip}	Skip mode operating quiescent current	$I_{OUT} = 0\text{ mA}$, Enable = V_{IN} (no switching)		80		μA
		$I_{OUT} = 0\text{ mA}$, Enable = V_{IN} (minimum switching)		90		μA
I_{SD}	Shut down current	$2.7\text{ V} \leq V_{IN} \leq 5.5\text{ V}$, Enable = 0 V			1	μA
V_{OUT}	Output voltage ⁽¹⁾	$I_{OUT} \leq 50\text{ mA}$, $2.7\text{ V} \leq V_{IN} < 5.5\text{ V}$	4.8	5	5.2	V
$V_{OUT(skip)}$	Skip mode output voltage	$I_{OUT} = 0\text{ mA}$, $2.7\text{ V} \leq V_{IN} \leq 5.5\text{ V}$		$V_{OUT} + 0.1$		V
F_{SW}	Switching frequency			1.5		MHz
SS_{TIME}	Soft-start time	From the rising edge of enable to 90% output		150		μs
OUTPUT CURRENT						
I_{OUT_nom}	Maximum output current	V_{OUT} remains from 4.8 V to 5.2 V, $3.1\text{ V} \leq V_{IN} \leq 5.5\text{ V}$	120			mA
		$3.3\text{ V} < V_{IN} < 5.5\text{ V}$	140			
I_{OUT_short}	Short circuit current ⁽²⁾	$V_{OUT} = 0\text{ V}$		80		mA
RIPPLE VOLTAGE						
V_R	Output ripple voltage	$I_{OUT} = 140\text{ mA}$		30		mV
ENABLE CONTROL						
V_{HI}	Logic high input voltage	$2.7\text{ V} \leq V_{IN} \leq 5.5\text{ V}$	1.3		V_{IN}	V
V_{LI}	Logic low input voltage		-0.2		0.4	V
I_{HI}	Logic high input current				1	μA
I_{LI}	Logic low input current				1	μA
THERMAL SHUTDOWN						
T_{SD}	Shutdown temperature			160		$^\circ\text{C}$
T_{RC}	Shutdown recovery			140		$^\circ\text{C}$

(1) When in skip mode, output voltage can exceed V_{OUT} spec because $V_{OUT(skip)} = V_{OUT} + 0.1$.

(2) The TPS60150 device has internal protection circuit to protect IC when V_{OUT} shorted to GND.

6.6 Typical Characteristics

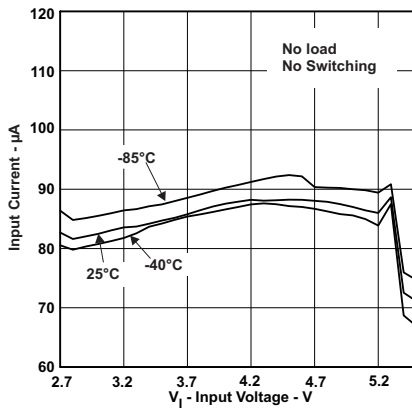


Figure 1. Quiescent Current vs Input Voltage

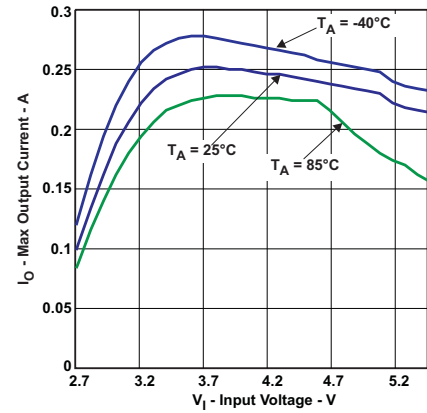


Figure 2. Maximum Output Current vs Input Voltage at Temperature

7 Detailed Description

7.1 Overview

The TPS60150 regulated charge pump provides a regulated output voltage for various input voltages. The TPS60150 device regulates the voltage across the flying capacitor to 2.5 V and controls the voltage drop of Q1 and Q2 while a conversion clock with 50% duty cycle drives the FETs.

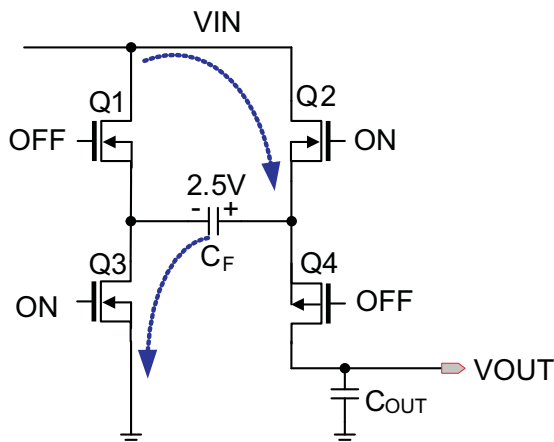


Figure 3. Charging Mode

During the first half cycle, Q2 and Q3 transistors are turned on and flying capacitor, C_F , will be charged to 2.5 V ideally.

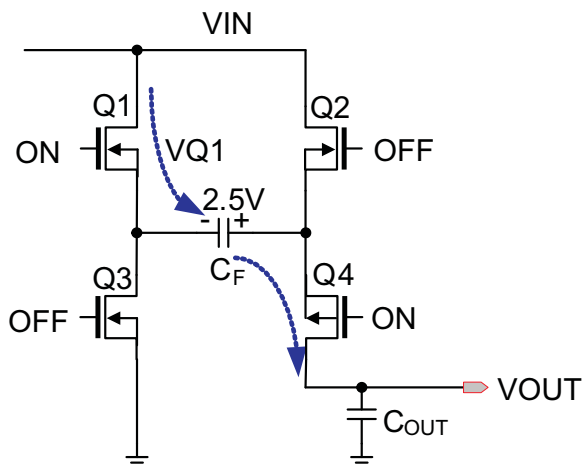


Figure 4. Discharging Mode

During the second half cycle, Q1 and Q4 transistors are turned on. Capacitor C_F will then be discharged to output.

Use Equation 1 to calculate the output voltage.

$$V_{OUT} = V_{IN} - V_{Q1} + V(C_F) - V_{Q4} = V_{IN} - V_{Q1} + 2.5 \text{ V} - V_{Q4} = 5 \text{ V}$$

(Ideal)

(1)

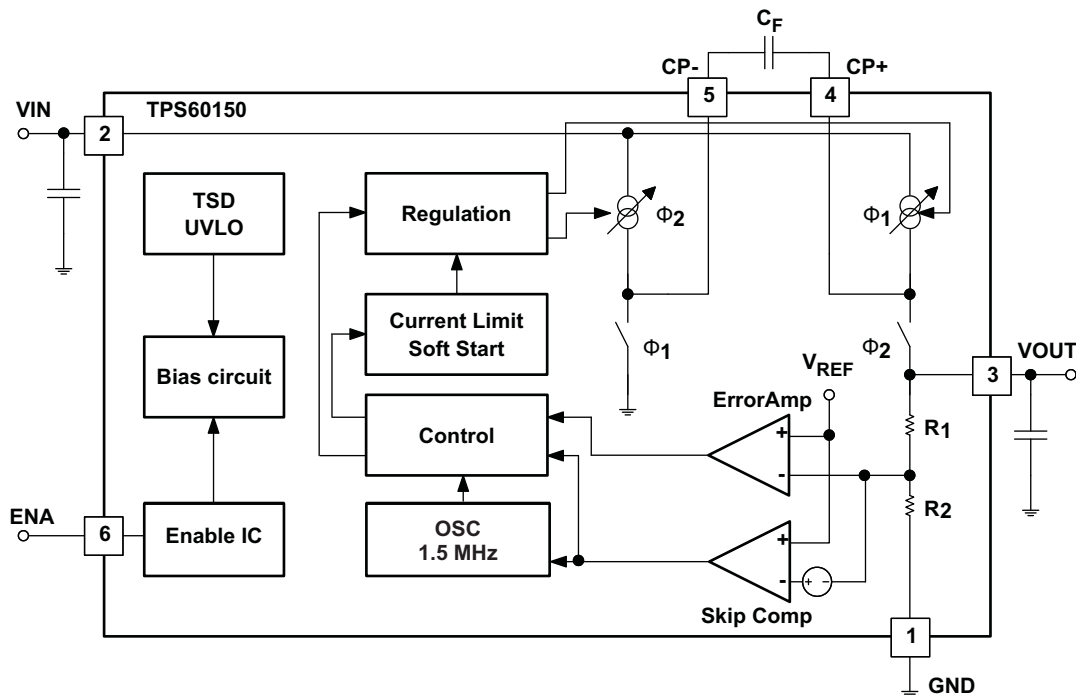
The output voltage is regulated by output feedback and an internally compensated voltage control loop.

TPS60150

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7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Enable

An enable pin on the regulator is used to place the device into an energy-saving shutdown mode. In this mode, the output is disconnected from the input, and the input quiescent current is reduced to 10 μ A maximum.

7.3.2 Undervoltage Lockout

When the input voltage drops, the undervoltage lockout prevents misoperation by switching off the device. The converter starts operation again when the input voltage exceeds the threshold, provided the enable pin is high.

7.3.3 Thermal Shutdown Protection

The regulator has thermal shutdown circuitry that protects it from damage caused by overload conditions. The thermal protection circuitry disables the output when the junction temperature reached approximately 160°C, allowing the device to cool. When the junction temperature cools to approximately 140°C, the output circuitry is automatically reenabled. Continuously running the regulator into thermal shutdown can degrade reliability. The regulator also provides current limit to protect itself and the load.

7.4 Device Functional Modes

7.4.1 Soft Start

An internal soft start limits the inrush current when the device is being enabled.

7.4.2 Normal Mode and Skip Mode Operation

The TPS60150 device has skip mode operation as shown in Figure 5. The TPS60150 device enters skip mode if the output voltage reaches $5\text{ V} + 0.1\text{ V}$ and the load current is less than 8 mA (typical). In skip mode, the TPS60150 device disables the oscillator and decreases the prebias current of the output stage to reduce the power consumption. Once the output voltage dips less than the threshold voltage of $5\text{ V} + 0.1\text{ V}$, the TPS60150 device begins switching to increase output voltage until the output reaches $5\text{ V} + 0.1\text{ V}$. When the output voltage dips less than 5 V , the TPS60150 device returns to normal pulse width modulation (PWM) mode; thereby reenabling the oscillator and increasing the prebias current of the output stage to supply output current.

The skip threshold voltage and current depend on input voltage and output current conditions.

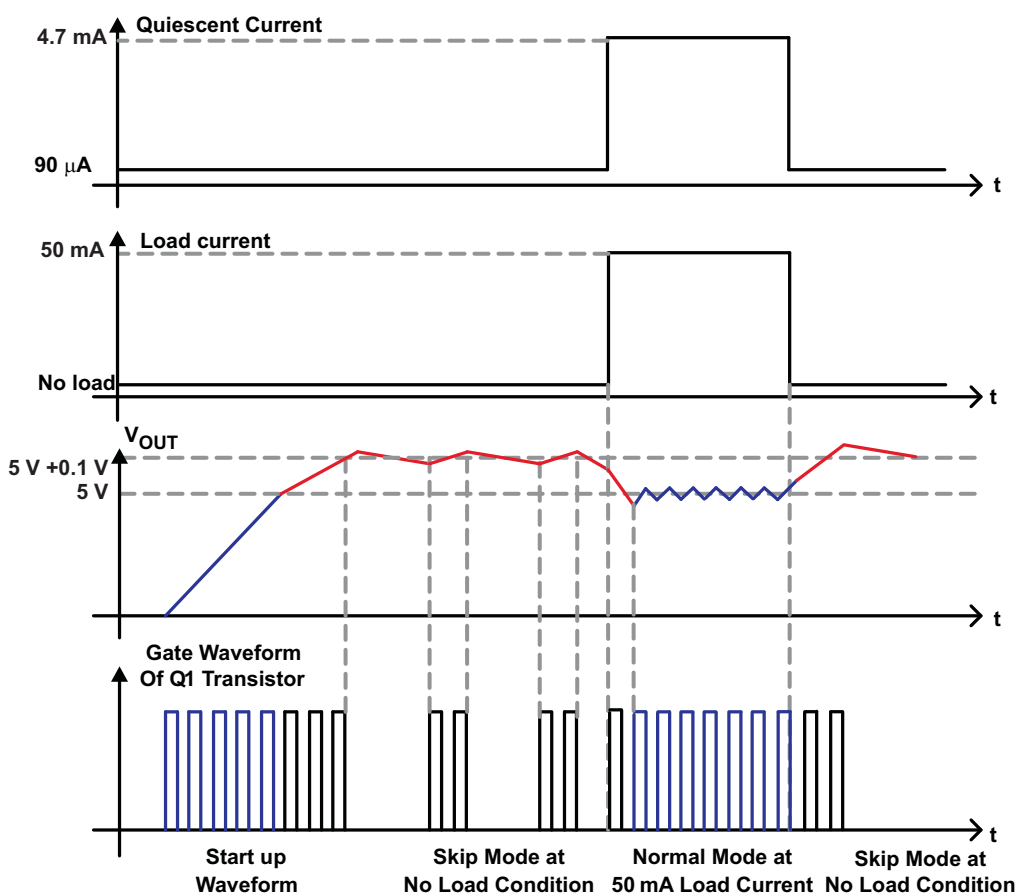


Figure 5. Normal Mode and Skip Mode Operation

7.4.3 Short Circuit Protection

The TPS60150 device has internal short circuit protection to protect the IC when the output is shorted to ground. To avoid damage when output is shorted to ground, the short circuit protection circuitry senses output voltage and clamps the maximum output current to 80 mA (typical).

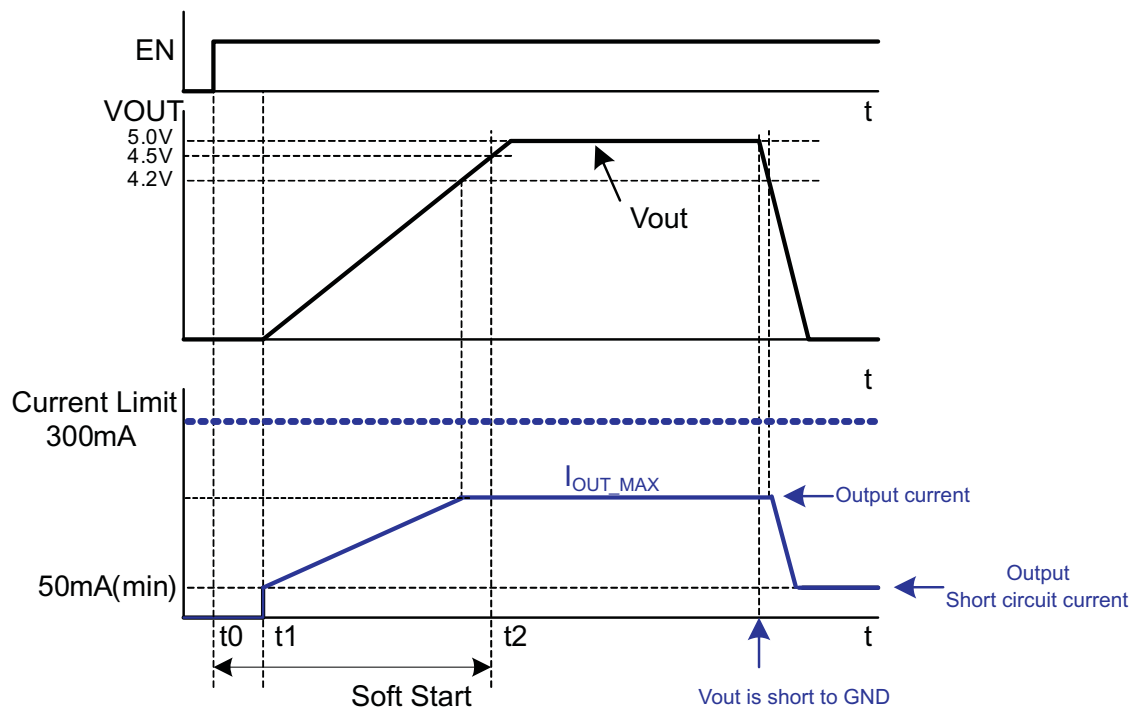
Device Functional Modes (continued)


Figure 6. Maximum Output Current Capability and Short Circuit Protection

8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

Most of today's battery-powered portable electronics allow and/or require data transfer with a PC. One of the fastest data transfer protocols is through USB On-the-Go (OTG). As [Figure 7](#) shows, the USB OTG circuitry in the portable device requires a 5-V power rail and up to 140 mA of current. The TPS60150 device may be used to provide a 5-V power rail in a battery powered system.

8.2 Typical Application

8.2.1 USB On the Go Circuitry

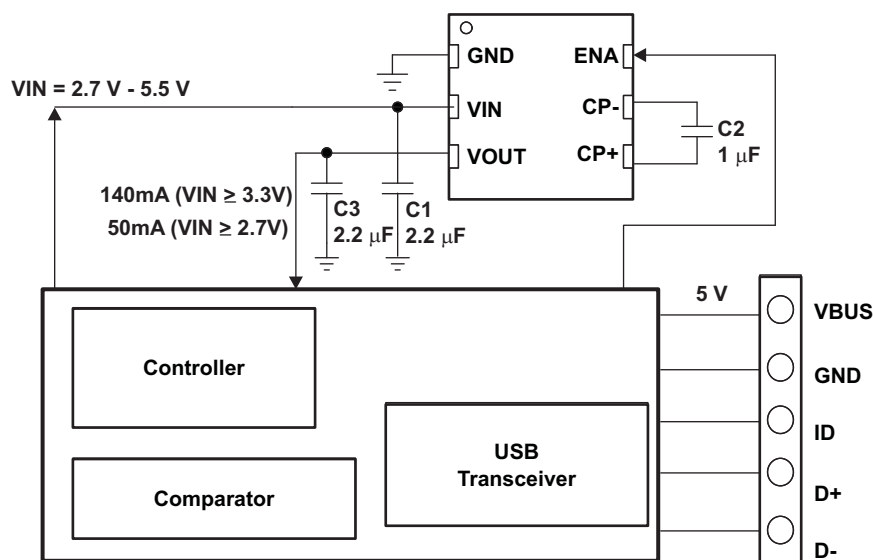


Figure 7. Application Circuit for OTG System

8.2.1.1 Design Requirements

The design guideline provides a component selection to operate the device within the [Recommended Operating Conditions](#).

8.2.1.2 Detailed Design Procedure

8.2.1.2.1 Capacitor Selection

For minimum output voltage ripple, the output capacitor (C_{OUT}) should be a surface-mount ceramic capacitor. Tantalum capacitors generally have a higher effective series resistance (ESR) and may contribute to higher output voltage ripple. Leaded capacitors also increase ripple due to the higher inductance of the package itself. To achieve the best operation with low input voltage and high load current, the input and flying capacitors (C_{IN} and C_F , respectively) should also be surface-mount ceramic types.

Typical Application (continued)

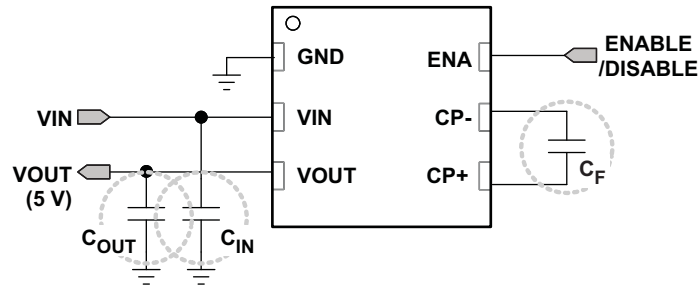


Figure 8. Capacitors

Generally, C_{FLY} can be calculated using [Equation 2](#).

$$Q_{\text{charging}} = C \times V = C_{FLY} \times \Delta V_{CFLY},$$

$$Q_{\text{discharging}} = i_{\text{discharge}} \times t = 2 \times I_{\text{LOAD(MAX)}} \times \left(\frac{T}{2}\right), \text{ half duty.} \quad (2)$$

Both equation should be same, $\therefore 2 \times I_{\text{LOAD(MAX)}} \times \left(\frac{T}{2}\right) = C_{FLY} \times \Delta V_{CFLY}$

$$\therefore C_{FLY} \geq \frac{2 \times I_{\text{LOAD(MAX)}} \times \left(\frac{T}{2}\right)}{\Delta V_{CFLY}} = \frac{I_{\text{LOAD(MAX)}}}{\Delta V_{CFLY} \times f} \quad (3)$$

If $I_{\text{LOAD}} = 140 \text{ mA}$, $f = 1.5 \text{ MHz}$, and $\Delta V_{CFLY} = 100 \text{ mV}$, the minimum value of the flying capacitor should be $1 \mu\text{F}$.

Output capacitance, C_{OUT} , is also strongly related to output ripple voltage and loop stability,

$$V_{\text{OUT(RIPPLE)}} = \frac{I_{\text{LOAD(MAX)}}}{(2 \times f \times C_{\text{OUT}})} + 2I_{\text{LOAD(MAX)}} \times \text{ESR}_{\text{COUT}} \quad (4)$$

The minimum output capacitance for all output levels is $2.2 \mu\text{F}$ due to control stability. Larger ceramic capacitors or low ESR capacitors can be used to lower the output ripple voltage.

Table 1. Suggested Capacitors (Input, Output, and Flying Capacitor)

VALUE	DIELECTRIC MATERIAL	PACKAGE SIZE	RATED VOLTAGE
4.7 μF	X5R or X7R	0603	10 V
2.2 μF	X5R or X7R	0603	10 V

The efficiency of the charge pump regulator varies with the output voltage, the applied input voltage and the load current.

Use [Equation 5](#) and [Equation 6](#) to calculate the approximate efficiency in normal operating mode is given by:

$$\text{Efficiency(\%)} = \frac{\text{PD(out)}}{\text{PD(in)}} \times 100 = \frac{V_{\text{OUT}} \times I_{\text{OUT}}}{V_{\text{IN}} \times I_{\text{IN}}} \times 100, I_{\text{IN}} = 2 \times I_{\text{OUT}} + I_{\text{Q}} \quad (5)$$

$$\text{Efficiency(\%)} = \frac{V_{\text{OUT}}}{2 \times V_{\text{IN}}} \times 100 \quad (I_{\text{IN}} = 2 \times I_{\text{OUT}}) \quad \text{Quiescent current was neglected.} \quad (6)$$

8.2.1.3 Application Curves

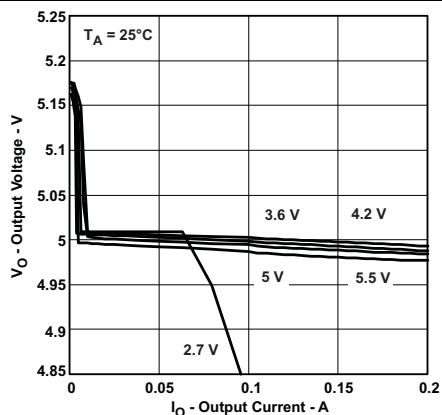


Figure 9. Output Voltage vs Output Current

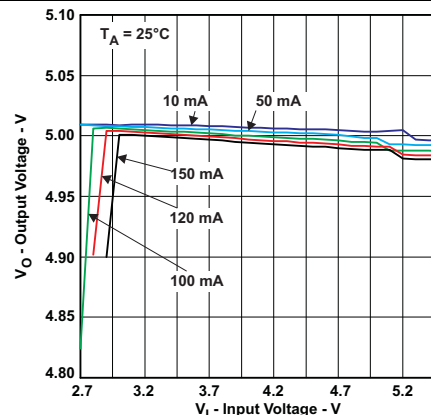


Figure 10. Output Voltage vs Input Voltage

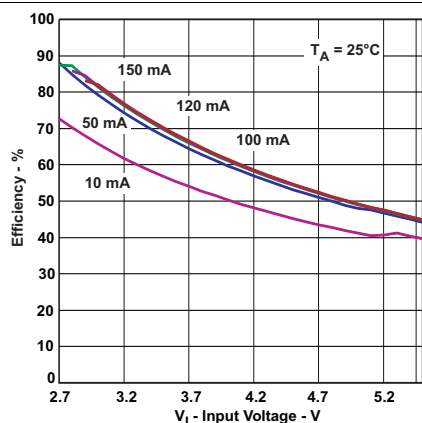


Figure 11. Efficiency vs Input Voltage

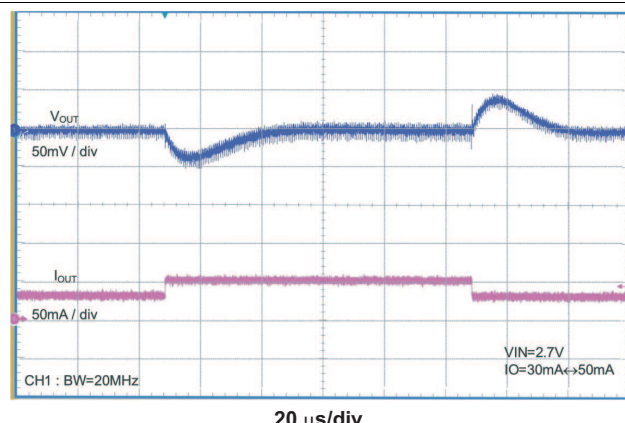


Figure 12. Load Transient Response
 $V_{IN} = 2.7\text{ V}$, $I_O = 30\text{ mA}$ to 50 mA

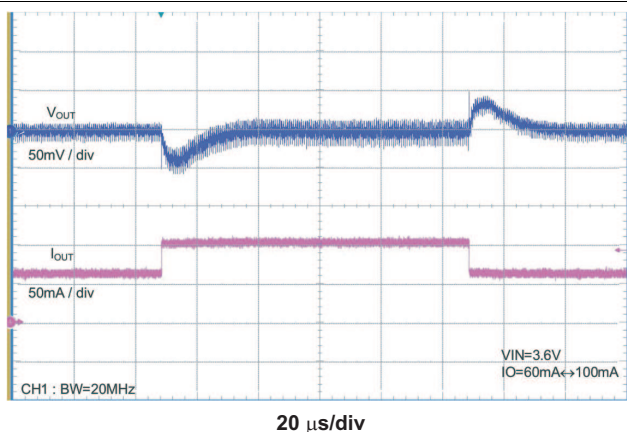


Figure 13. Load Transient Response
 $V_{IN} = 3.6\text{ V}$, $I_O = 60\text{ mA}$ to 100 mA

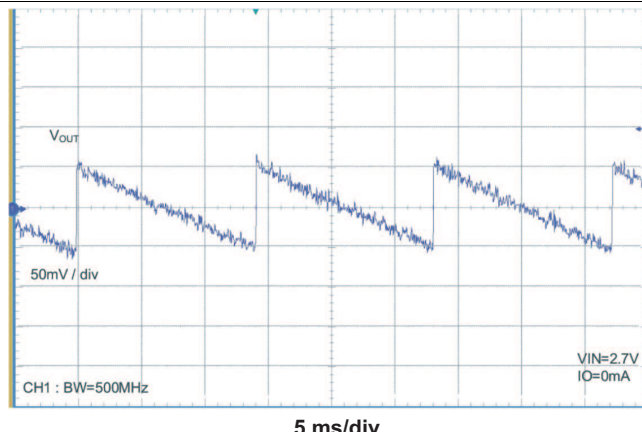


Figure 14. Output Ripple Voltage (Skip Mode)
 $V_{IN} = 2.7\text{ V}$, $I_O = 0\text{ mA}$

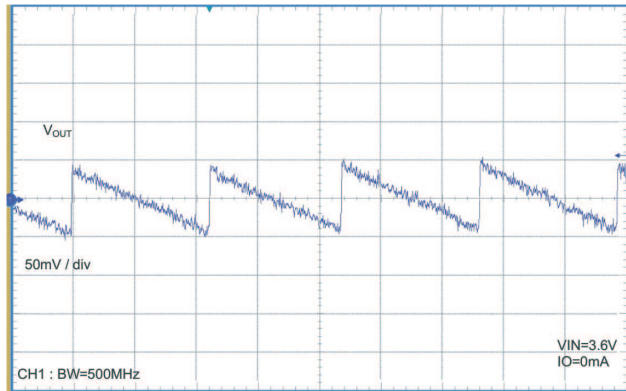


Figure 15. Output Ripple Voltage (Skip Mode)
 $V_{IN} = 3.6\text{ V}$, $I_O = 0\text{ mA}$

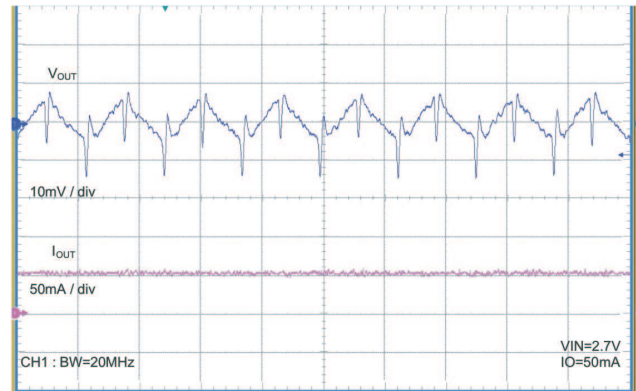


Figure 16. Output Ripple Voltage (Normal Mode)
 $V_{IN} = 2.7\text{ V}$, $I_O = 50\text{ mA}$

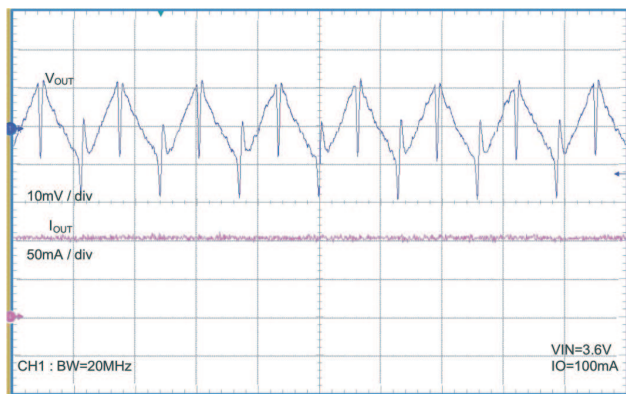


Figure 17. Output Ripple (Normal Mode)
 $V_{IN} = 3.6\text{ V}$, $I_O = 100\text{ mA}$

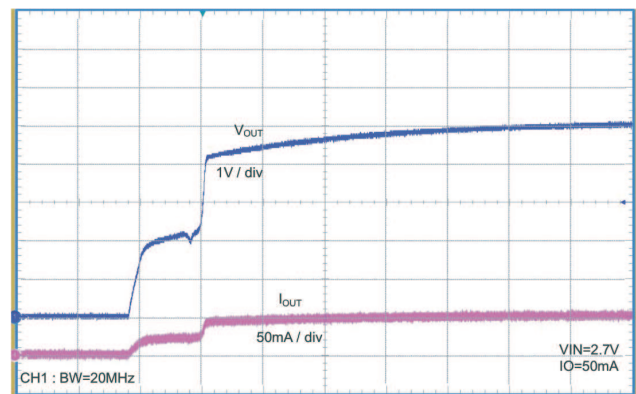


Figure 18. Power On
 $V_{IN} = 2.7\text{ V}$, $I_O = 50\text{ mA}$

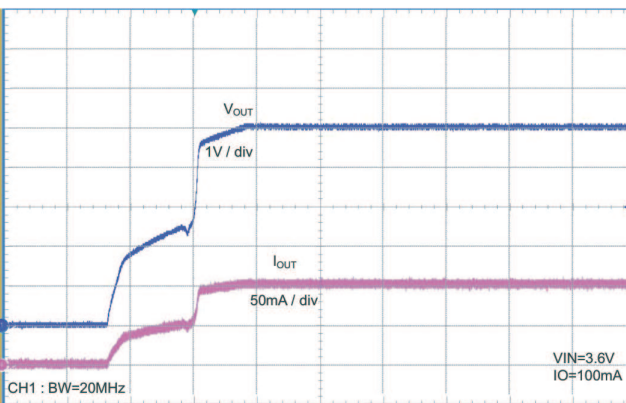


Figure 19. Power On
 $V_{IN} = 3.6\text{ V}$, $I_O = 100\text{ mA}$

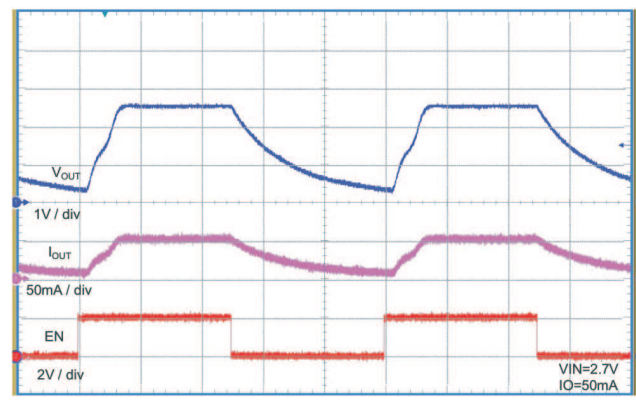
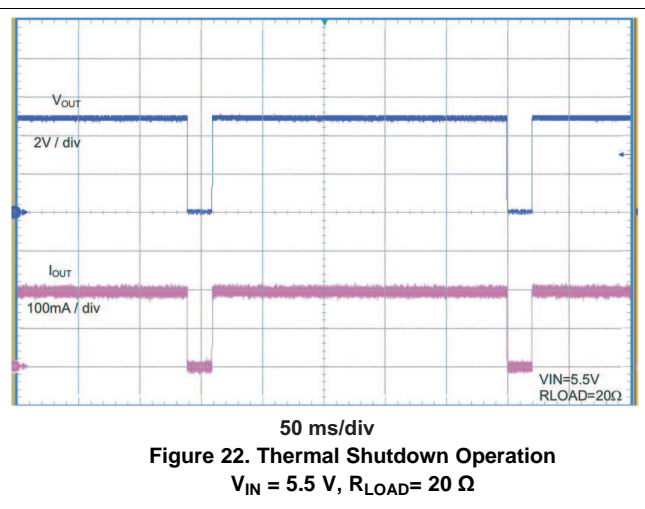
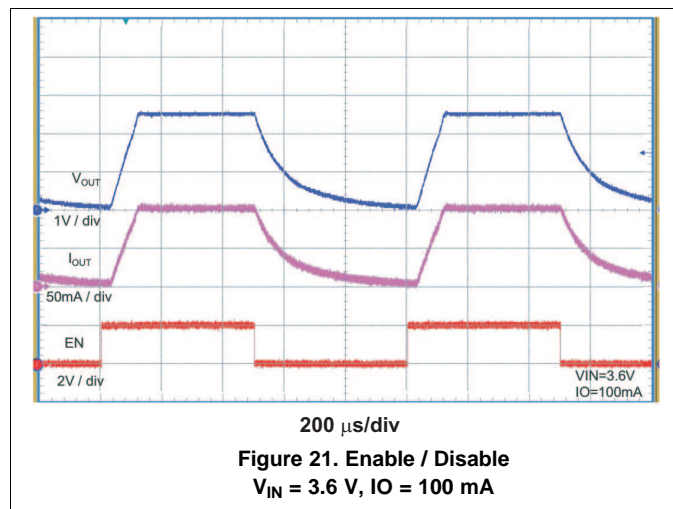
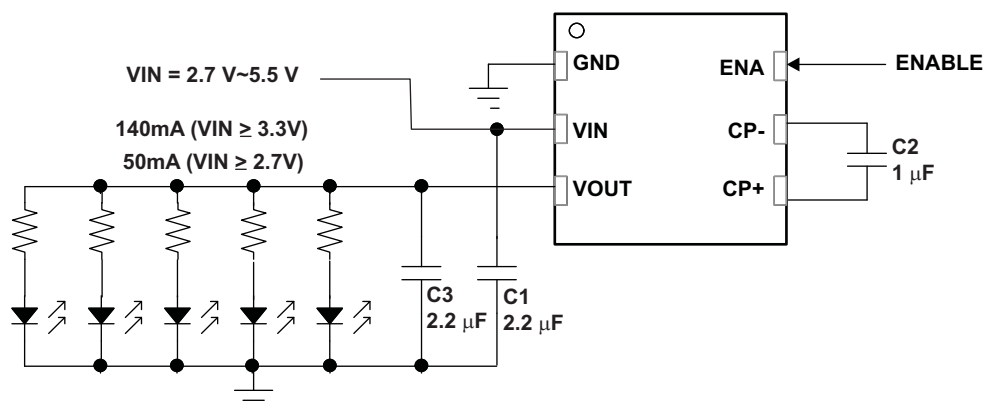


Figure 20. Enable / Disable
 $V_{IN} = 2.7\text{ V}$, $I_O = 50\text{ mA}$



8.2.2 System Example

Low-cost portable electronics with small LCD displays require a low-cost solution for providing the WLED backlight. As shown in [Figure 23](#), the TPS60150 device can also be used to drive several WLEDs in parallel, with the help of ballast resistors.



9 Power Supply Recommendations

The TPS60150 device has no special requirements for its input power supply. The input power supply's output current must be rated according to the supply voltage, output voltage and output current of the TPS60150 device.

10 Layout

10.1 Layout Guidelines

Large transient currents flow in the VIN, VOUT, and GND traces. To minimize both input and output ripple, keep the capacitors as close as possible to the regulator using short, direct circuit traces.

10.2 Layout Example

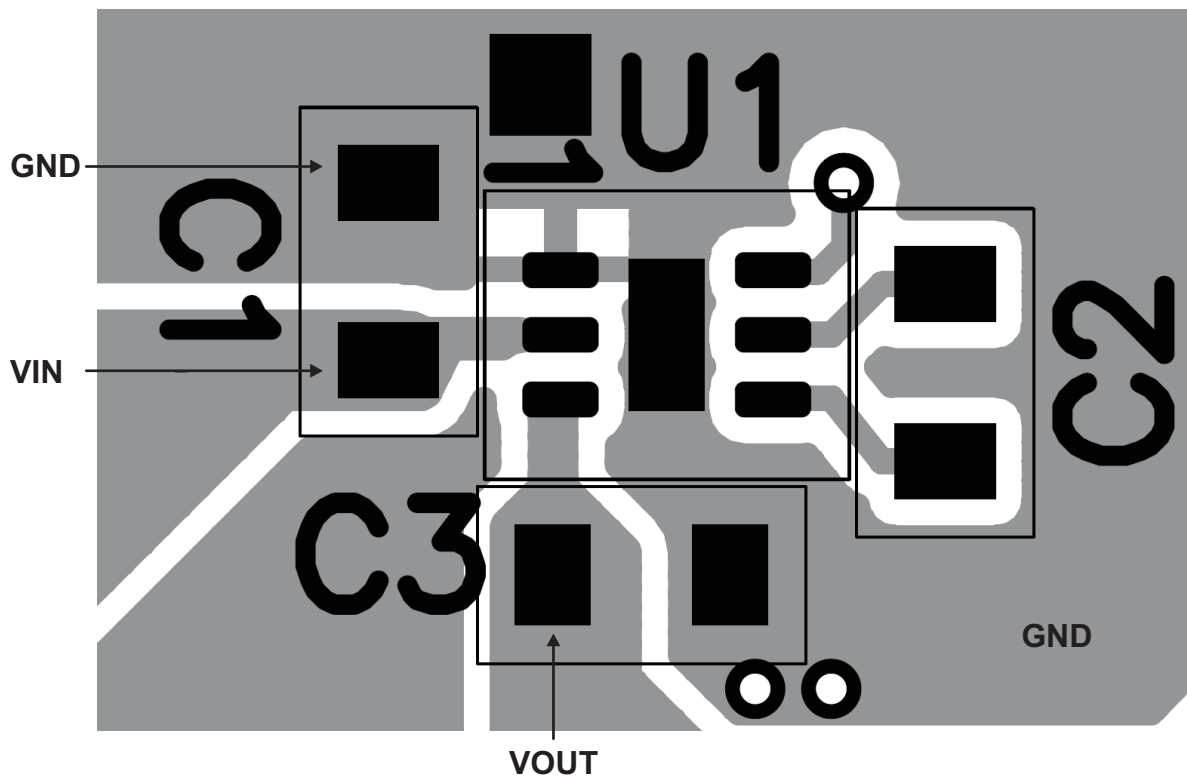


Figure 24. Recommended PCB Layout

11 Device and Documentation Support

11.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

TI E2E™ Online Community *TI's Engineer-to-Engineer (E2E) Community*. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support *TI's Design Support* Quickly find helpful E2E forums along with design support tools and contact information for technical support.

11.2 Trademarks

E2E is a trademark of Texas Instruments.
All other trademarks are the property of their respective owners.

11.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

11.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS60150DRVR	Active	Production	WSO (DRV) 6	3000 LARGE T&R	Yes	Call TI Nipdauag Nipdau	Level-1-260C-UNLIM	-40 to 85	CGO
TPS60150DRVR.A	Active	Production	WSO (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGO
TPS60150DRVR.B	Active	Production	WSO (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGO
TPS60150DRVRG4	Active	Production	WSO (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGO
TPS60150DRVRG4.A	Active	Production	WSO (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGO
TPS60150DRVRG4.B	Active	Production	WSO (DRV) 6	3000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGO
TPS60150DRVT	Active	Production	WSO (DRV) 6	250 SMALL T&R	Yes	Call TI Nipdauag Nipdau	Level-1-260C-UNLIM	-40 to 85	CGO
TPS60150DRVT.A	Active	Production	WSO (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGO
TPS60150DRVT.B	Active	Production	WSO (DRV) 6	250 SMALL T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	CGO

(1) **Status:** For more details on status, see our [product life cycle](#).

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS60150DRVR	WSO	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS60150DRVR	WSO	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS60150DRVRG4	WSO	DRV	6	3000	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2
TPS60150DRVT	WSO	DRV	6	250	180.0	8.4	2.3	2.3	1.15	4.0	8.0	Q2

TAPE AND REEL BOX DIMENSIONS

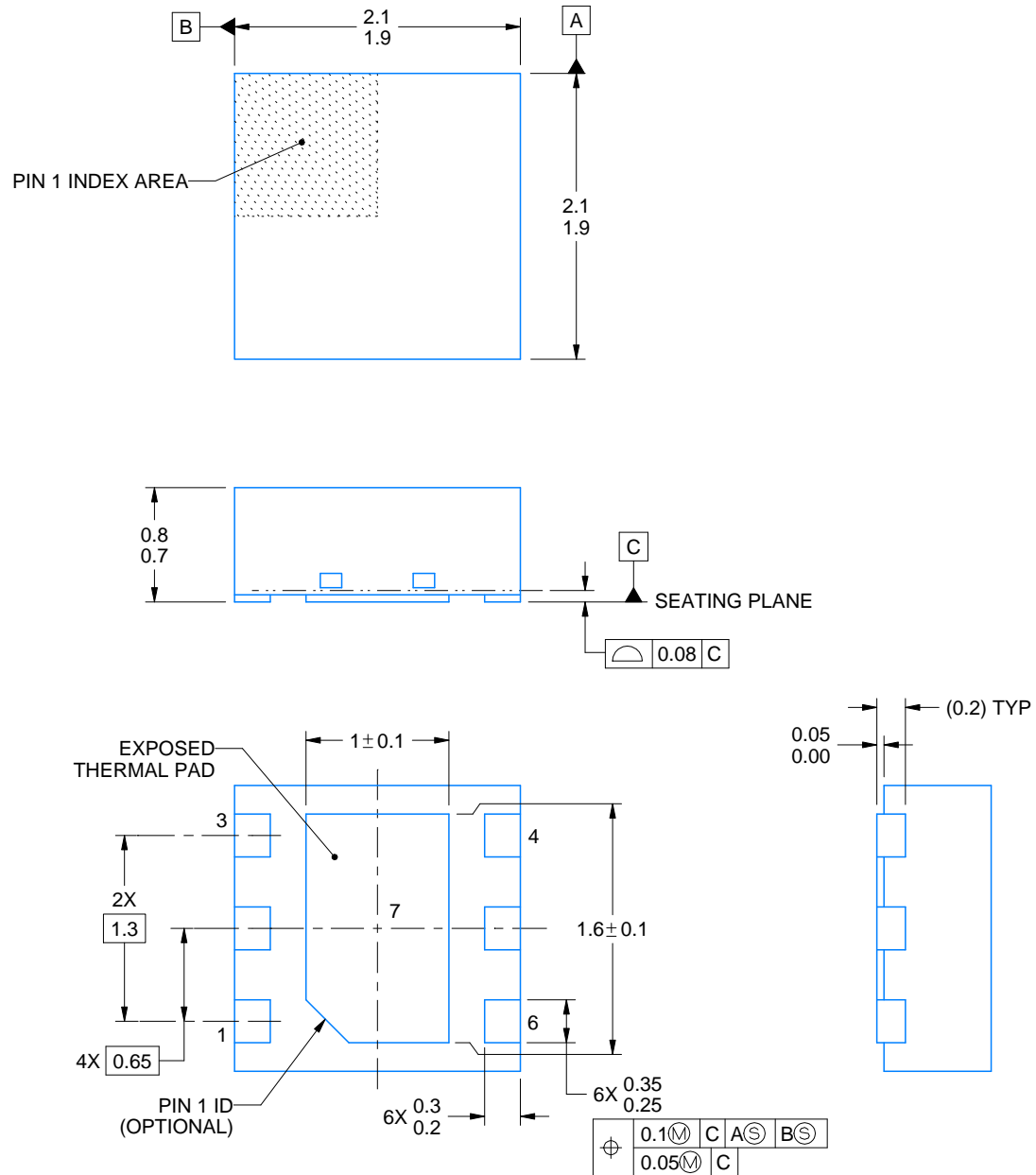
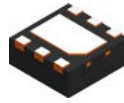


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS60150DRVR	WSON	DRV	6	3000	182.0	182.0	20.0
TPS60150DRVR	WSON	DRV	6	3000	213.0	191.0	35.0
TPS60150DRVRG4	WSON	DRV	6	3000	182.0	182.0	20.0
TPS60150DRVT	WSON	DRV	6	250	182.0	182.0	20.0



Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



4222173/B 04/2018

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

EXAMPLE BOARD LAYOUT

DRV0006A

WSN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
SCALE:25X



SOLDER MASK DETAILS

4222173/B 04/2018

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/sluea271).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DRV0006A

WSN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



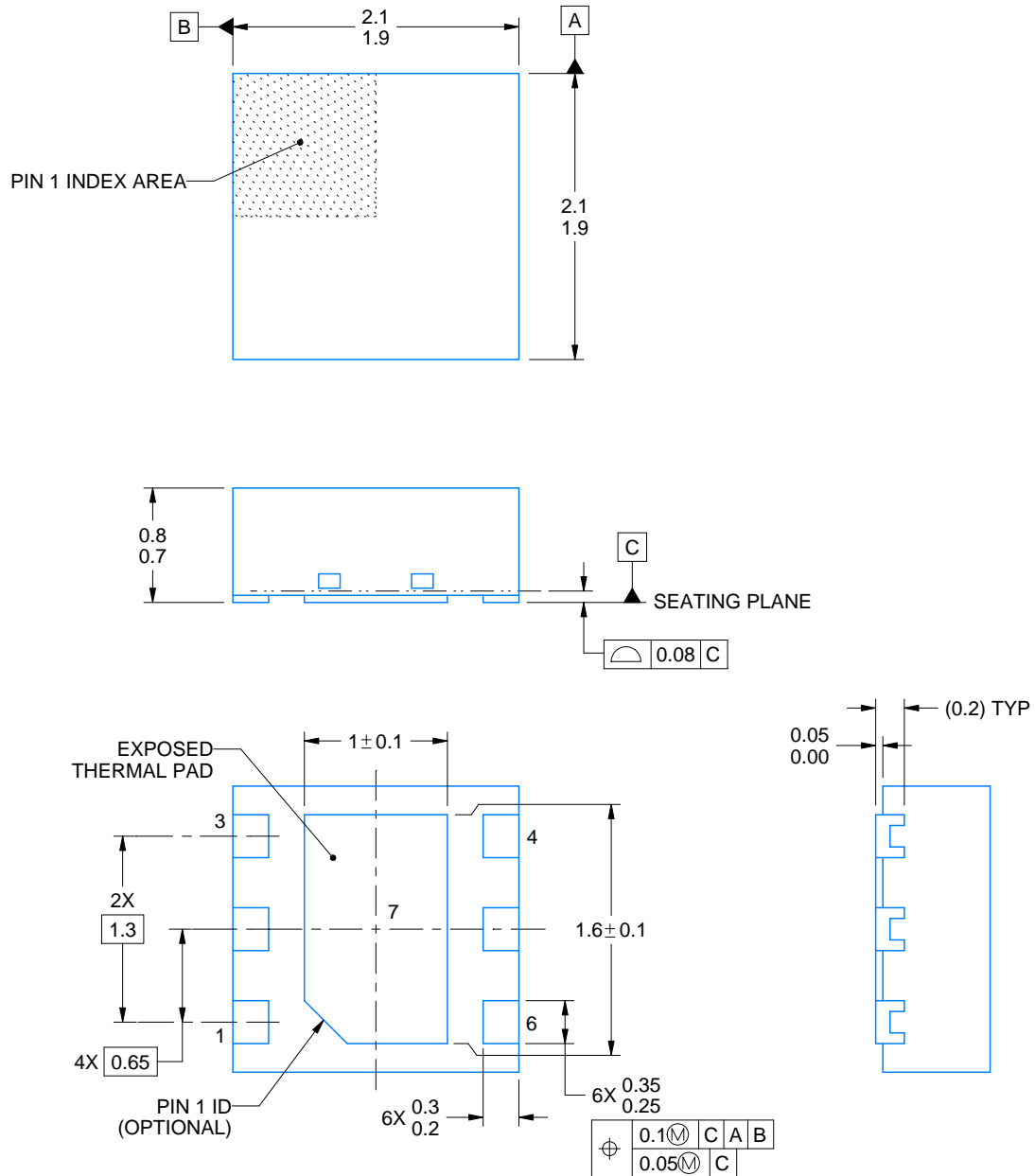
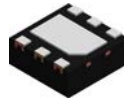
SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4222173/B 04/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.



4225563/A 12/2019

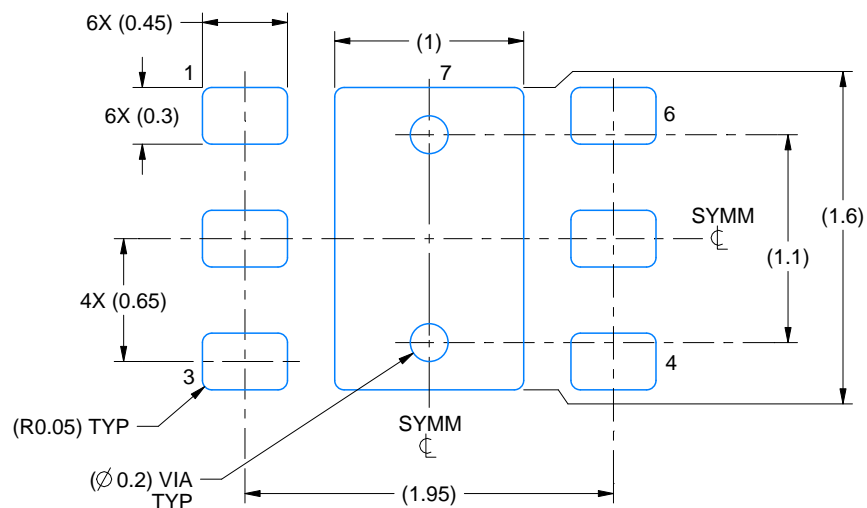
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for thermal and mechanical performance.

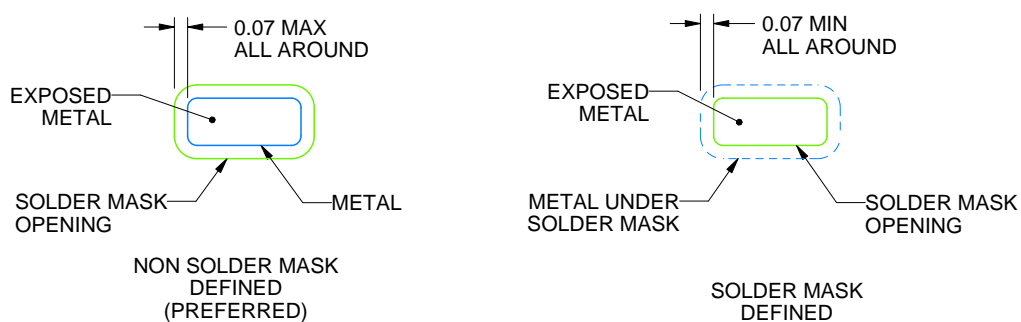
DRV0006D

WSON - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:25X



SOLDER MASK DETAILS

4225563/A 12/2019

NOTES: (continued)

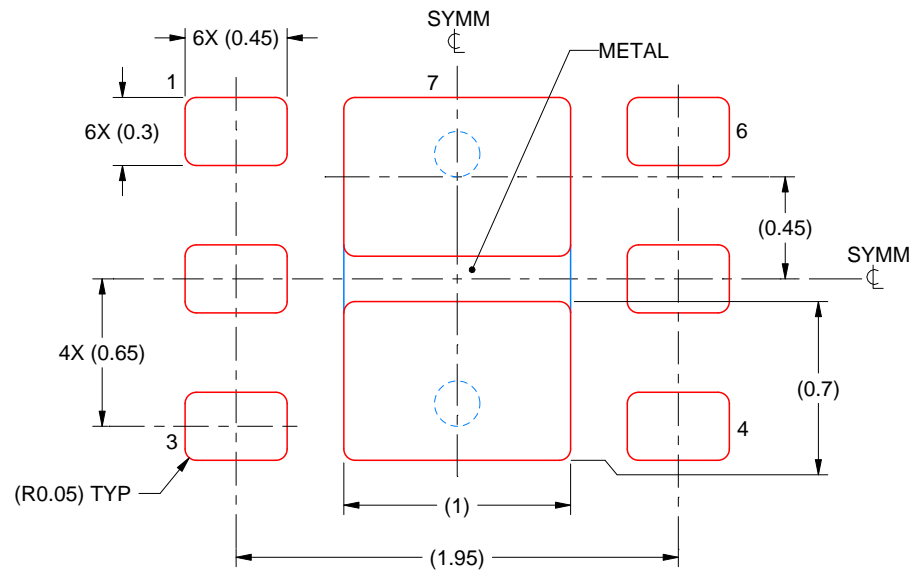
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If some or all are implemented, recommended via locations are shown.

EXAMPLE STENCIL DESIGN

DRV0006D

WSN - 0.8 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD #7
88% PRINTED SOLDER COVERAGE BY AREA UNDER PACKAGE
SCALE:30X

4225563/A 12/2019

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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